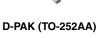
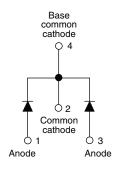


Vishay Semiconductors

### Schottky Rectifier, 2 x 3 A







PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I <sub>F(AV)</sub>	2 x 3 A					
$V_{R}$	50 V, 60 V					
V <sub>F</sub> at I <sub>F</sub>	0.65 V					
I <sub>RM</sub>	15 mA at 125 °C					
T <sub>J</sub> max.	150 °C					
Diode variation	Common cathode					
E <sub>AS</sub>	6 mJ					

### **FEATURES**

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- $\bullet$  Meets MSL level 1, per J-STD-020, LF maximum peak of 260  $^{\circ}\text{C}$

### **DESCRIPTION**

The VS-MBRD650CTPbF, VS-MBRD660CTPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	6	А						
V <sub>RRM</sub>		50/60	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	490	А						
V <sub>F</sub>	3 Apk, T <sub>J</sub> = 125 °C (per leg)	0.65	V						
TJ	Range	- 40 to 150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRD650CTPbF	VS-MBRD660CTPbF	UNITS					
Maximum DC reverse voltage	$V_{R}$	50	60	V					
Maximum working peak reverse voltage	$V_{RWM}$	30	00	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDIT	VALUES	UNITS				
Maximum average per leg forward current per device per device			50 % duty cycle at T <sub>C</sub> = 128 °C, rectangular waveform		3.0	A			
		I <sub>F(AV)</sub>	30 % duty cycle at 16 = 120 0, 16	6					
Maximum peak one cycle non-repetitive surge current See fig. 7		_	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	490	A			
		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	75				
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 12 mH		6	mJ			
Repetitive avalanche curre	nt per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical		0.6	Α			

Document Number: 94314 Revision: 14-Jan-11

# VS-MBRD650CTPbF, VS-MBRD660CTPbF

Vishay Semiconductors

Schottky Rectifier, 2 x 3 A



Document Number: 94314

Revision: 14-Jan-11

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS					
		3 A	T <sub>.1</sub> = 25 °C	0.7					
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	6 A	1j=25 C	0.9	V				
See fig. 1	VFM (1)	3 A	T <sub>.1</sub> = 125 °C	0.65	V				
		6 A	1J = 125 C	0.85					
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	0.1	mA				
See fig. 2	IRM (')	T <sub>J</sub> = 125 °C	v <sub>R</sub> = nateu v <sub>R</sub>	15	IIIA				
Typical junction capacitance per leg	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	ge 100 kHz to 1 MHz), 25 °C	145	pF				
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 r	5.0	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs					

#### Note

 $<sup>^{(1)}</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 40 to 150	°C		
Maximum thermal resistance, per leg junction to case per device		D	DC operation	6			
		R <sub>thJC</sub>	See fig. 4	3	°C/W		
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		80	5,		
Approximate weight				0.3	g		
Approximate weight				0.01	OZ.		
Marking device			Coop et de D. DAV (eleviter to TO 252AA)	MBRD650CT			
			Case style D-PAK (similar to TO-252AA)	MBRD660CT			

### Note

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 2 x 3 A

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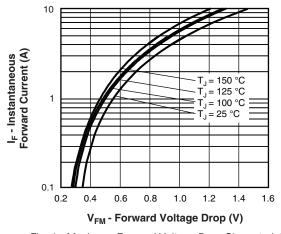


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

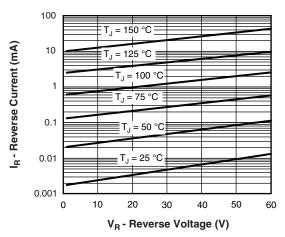


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

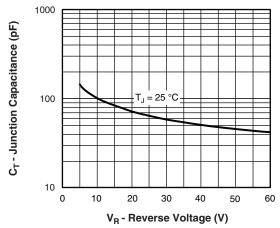


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

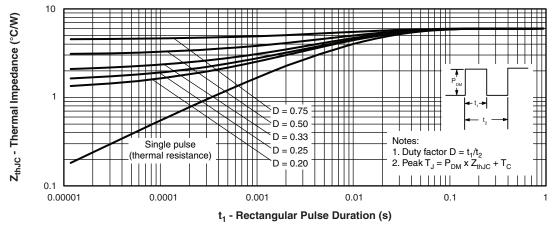


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

# VS-MBRD650CTPbF, VS-MBRD660CTPbF

## Vishay Semiconductors

Schottky Rectifier, 2 x 3 A



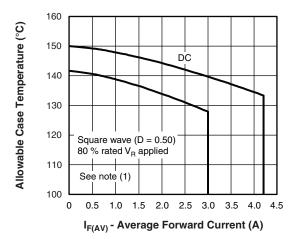


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

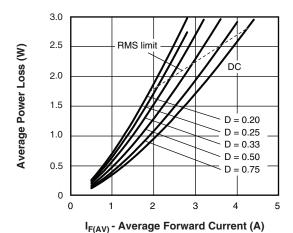


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

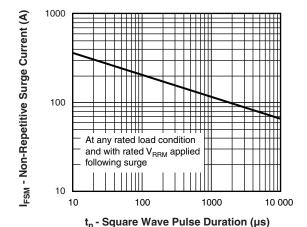


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times \text{R}_{\text{th,JC}}; \\ \text{Pd} = \text{Forward power loss} = I_{\text{F(AV)}} \times \text{V}_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 6)}; \\ \text{Pd}_{\text{REV}} = \text{Inverse power loss} = \text{V}_{\text{R1}} \times \text{I}_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } \text{V}_{\text{R1}} = 80 \text{ \% rated V}_{\text{R}} \\ \end{array}$ 

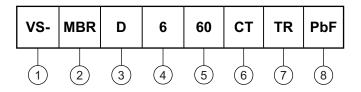
## VS-MBRD650CTPbF, VS-MBRD660CTPbF

Schottky Rectifier, 2 x 3 A

Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Schottky MBR series

3 - D = TO-252AA (D-PAK)

- Current rating (6 = 6 A)

50 = 50 V 50 = 60 V

6 - CT = Center tap (dual)

7 • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95059					
Packaging information	www.vishay.com/doc?95033					



### Vishay Semiconductors

**NOTES** 

3

2

MAX.

0.410

0.070

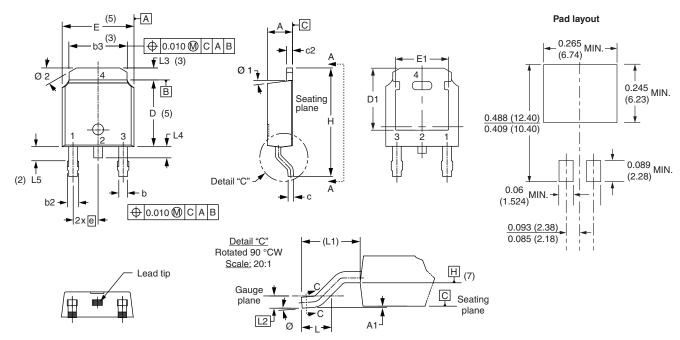
0.050

0.040

0.060

# **D-PAK (TO-252AA)**

#### **DIMENSIONS** in millimeters and inches



Ī	SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		
	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX
ſ	Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC
ſ	A1	-	0.13		0.005			Н	9.40	10.41	0.370	0.41
Ī	b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.07
Ī	b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.
ſ	b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC
Ī	С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.05
Ī	c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.04
ſ	D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.06
Ī	D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°
ſ	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°
Ī	E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°

### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



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Vishay

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Revision: 02-Oct-12 Document Number: 91000